

PS7522-1A,-2A,PS7522L-1A,-2A

6, 8-PIN DIP, SLOW SWITCHING TYPE 1-ch, 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7522-1A, -2A and PS7522L-1A, -2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for equipments which are necessary to prevent some noise, because of their slow switching speed at turn-on or turn-off.

The PS7522L-1A, -2A have a surface mount type lead.

★ FEATURES

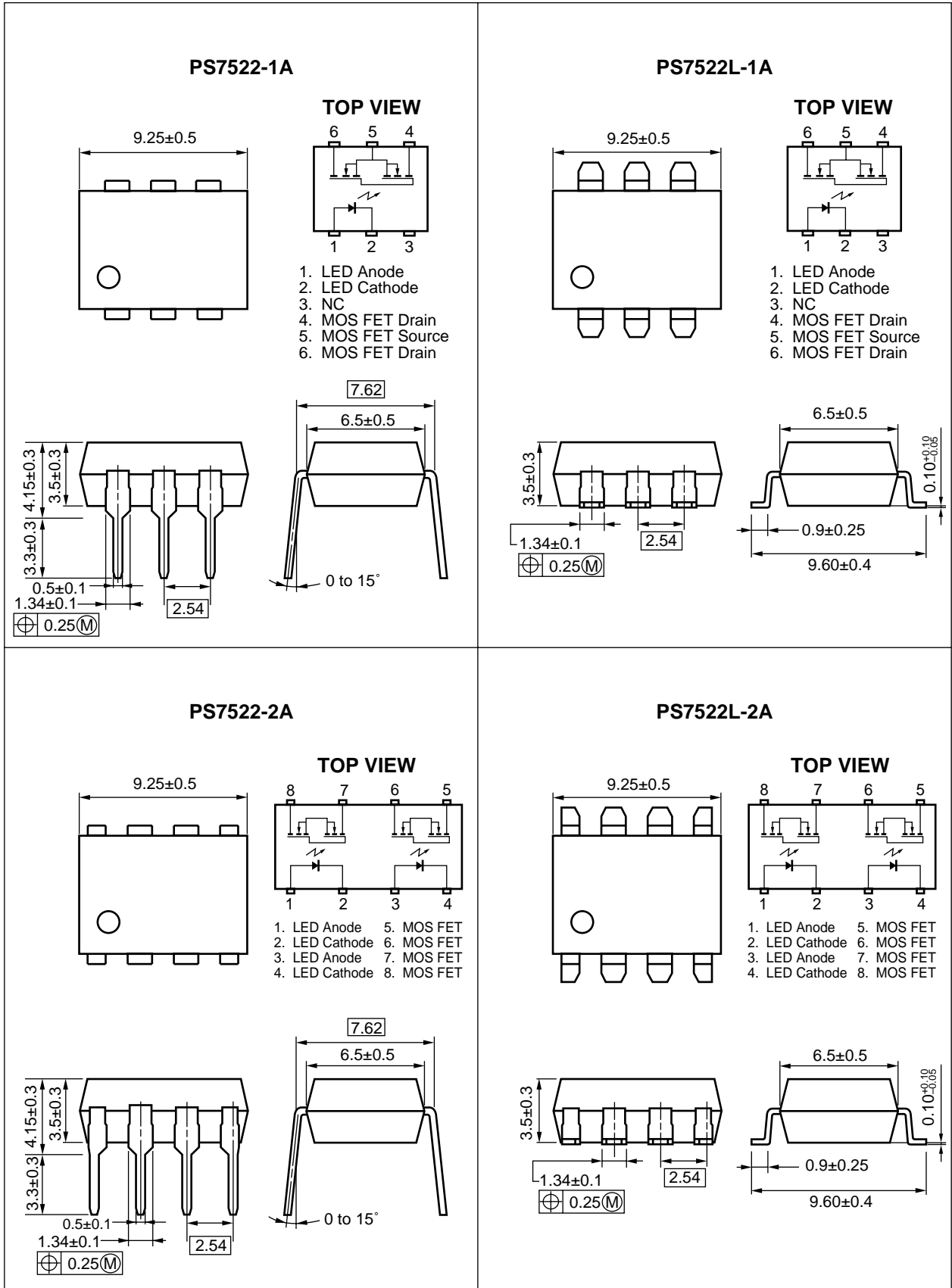
- 1 channel type (1 a output) or 2 channel type (1 a + 1 a output)
- Low LED operating current ($I_f = 1 \text{ mA}$)
- Designed for AC/DC switching line changer
- Small package (6, 8-pin DIP)
- Slow turn-on time, slow turn-off time ($t_{on} = 12 \text{ ms MAX.}$, $t_{off} = 6.5 \text{ ms MAX.}$)
- Low offset voltage
- PS7522L-1A, -2A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PACKAGE DIMENSIONS (in millimeters)



★ **ORDERING INFORMATION**

| Part Number | Package | Packing Style | Application Part Number ^{*1} |
|---------------|-----------|------------------------------|---------------------------------------|
| PS7522-1A | 6-pin DIP | Magazine case 50 pcs | PS7522-1A |
| PS7522L-1A | | | PS7522L-1A |
| PS7522L-1A-E3 | | Embossed Tape 1 000 pcs/reel | |
| PS7522L-1A-E4 | | | |
| PS7522-2A | 8-pin DIP | Magazine case 50 pcs | PS7522-2A |
| PS7522L-2A | | | PS7522L-2A |
| PS7522L-2A-E3 | | Embossed Tape 1 000 pcs/reel | |
| PS7522L-2A-E4 | | | |

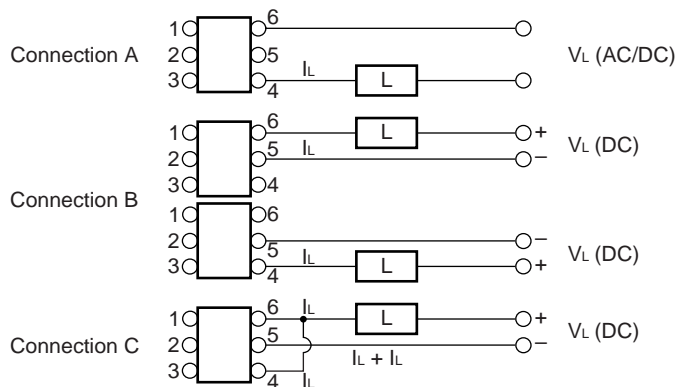
*1 For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

| Parameter | | Symbol | Ratings | | Unit |
|---------------------------------|--|------------------|--------------------------|--------------------------|---------|
| | | | PS7522-1A, PS7522L-1A | PS7522-2A, PS7522L-2A | |
| Diode | Forward Current (DC) | I _F | 50 | | mA |
| | Reverse Voltage | V _R | 5.0 | | V |
| | Power Dissipation | P _D | 50 | | mW/ch |
| | Peak Forward Current ^{*1} | I _{FP} | 1 | | A |
| MOS FET | Break Down Voltage | V _L | 200 | | V |
| | Continuous Load Current ^{*2} | Connection A | 200 | | mA |
| | | Connection B | 350 | – | |
| | | Connection C | 400 | – | |
| | Pulse Load Current ^{*3} (AC/DC Connection) | I _{LP} | 400 | | mA |
| Power Dissipation | P _D | 560 | 375 | mW/ch | |
| Isolation Voltage ^{*4} | | BV | 1 500 | | Vr.m.s. |
| Total Power Dissipation | | P _T | 610 | 850 | mW |
| Operating Ambient Temperature | | T _A | –40 to +80 | | °C |
| Storage Temperature | | T _{stg} | –40 to +100 | | °C |

*1 PW = 100 μs, Duty Cycle = 1 %

*2 Conditions: I_F ≥ 2 mA. The following types of load connections are available.



*3 PW = 100 ms, 1 shot

*4 AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

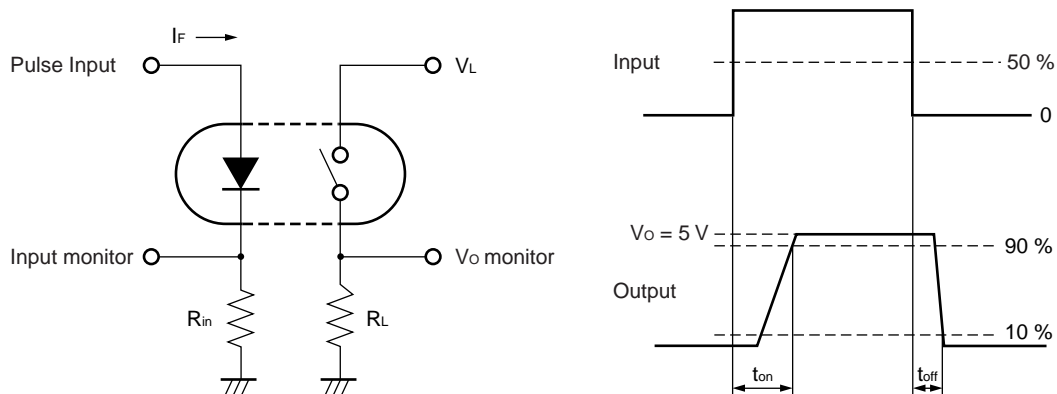
RECOMMENDED OPERATING CONDITIONS (T_A = 25 °C)

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
|-----------------------|----------------|------|------|------|------|
| LED Operating Current | I _F | 1 | 10 | 20 | mA |
| LED Off Voltage | V _F | 0 | | 0.5 | V |

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

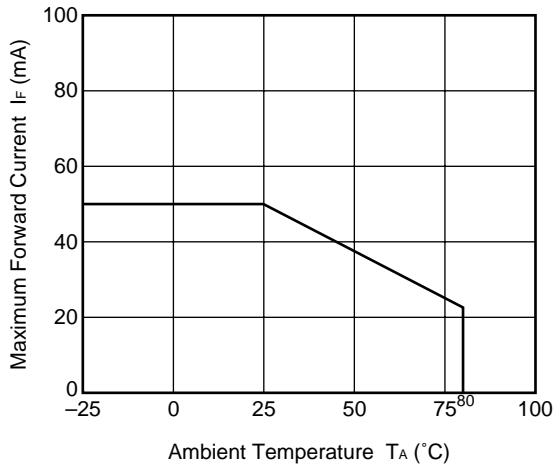
| Parameter | | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------|---------------------------|-------------------|--|---|-----------------|-------|-------|
| Diode | Forward Voltage | V _F | I _F = 1.4 mA | | 1.1 | 1.4 | V |
| | Reverse Current | I _R | V _R = 5 V | | | 5.0 | μA |
| MOS FET | Off-state Leakage Current | I _{Loff} | V _D = 200 V | | 0.03 | 1.0 | μA |
| | Output Capacitance | C _{out} | V _D = 0 V, f = 1 MHz | | 165 | | pF/ch |
| Coupled | LED On-state Current | I _{Fon} | I _L = 200 mA | | | 1.0 | mA |
| | On-state Resistance | R _{on1} | I _F = 1.4 mA, I _L = 10 mA | | 3.0 | 5.0 | Ω |
| | | R _{on2} | I _F = 10 mA, I _L = 200 mA, t ≤ 20 ms | | | | |
| | Turn-on Time *1 | t _{on} | I _F = 1.4 mA, V _O = 60 V, PW ≥ 50 ms | | 8.5 | 12 | ms |
| | Rise Time | t _r | | 0.80 | 2.78 | | |
| | Turn-off Time *1 | t _{off} | | | 3.0 | 6.5 | |
| | Fall Time | t _f | | 0.4 | 0.8 | | |
| | Isolation Resistance | R _{I-O} | | V _{I-O} = 1.0 kV _{DC} | 10 ⁹ | | Ω |
| Isolation Capacitance | C _{I-O} | | V = 0 V, f = 1 MHz | | 1.1 | pF/ch | |

*1 Test Circuit for Switching Time

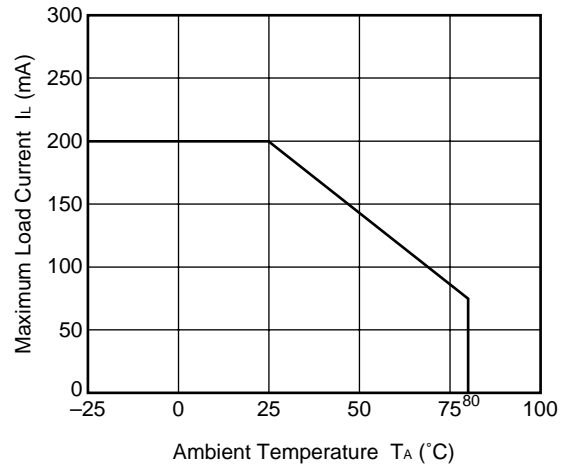


★ TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

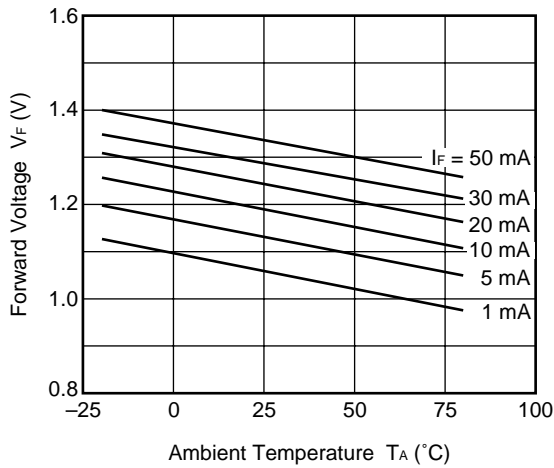
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



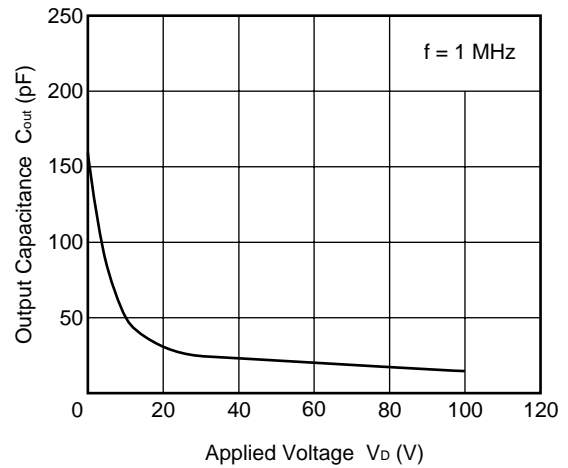
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



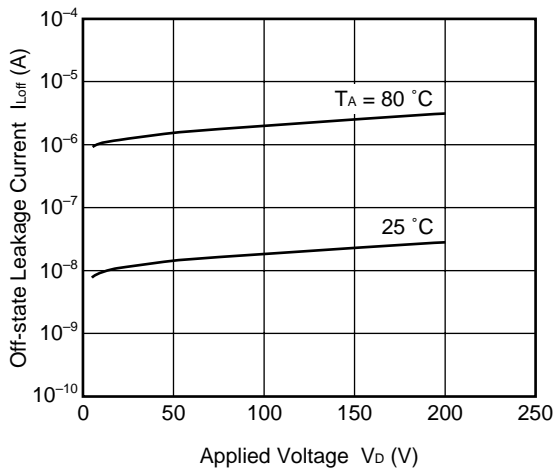
FORWARD VOLTAGE vs. AMBIENT TEMPERATURE



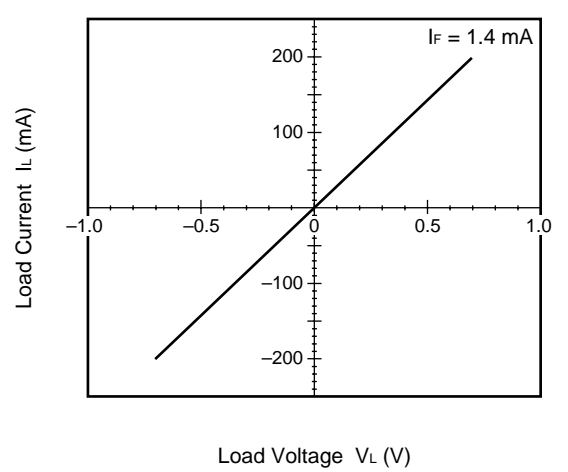
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



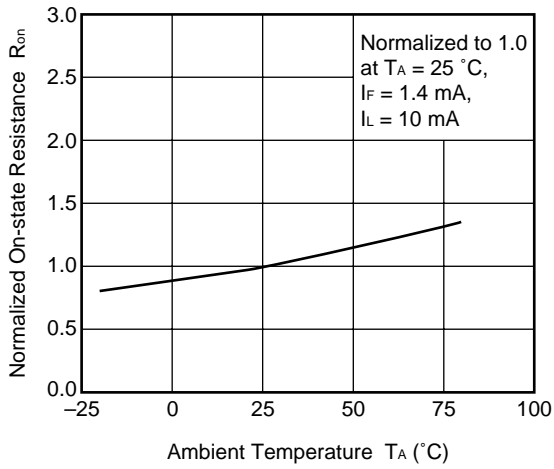
OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



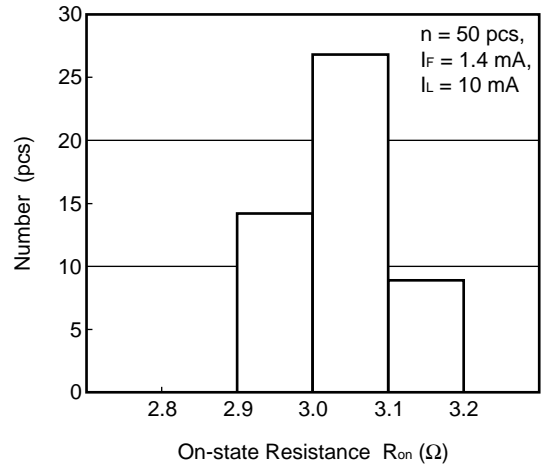
LOAD CURRENT vs. LOAD VOLTAGE



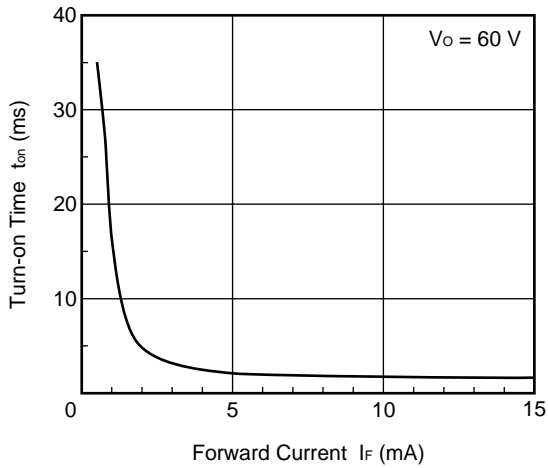
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



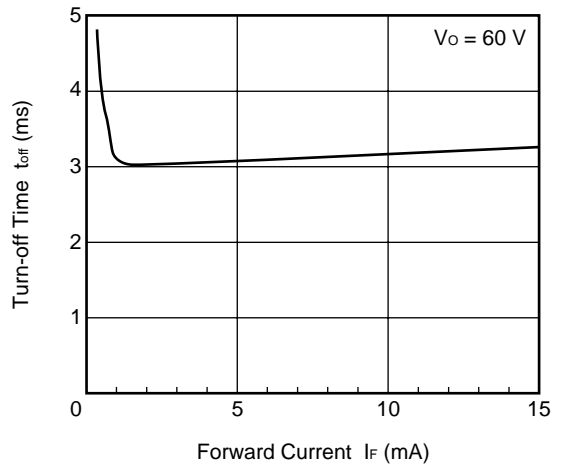
ON-STATE RESISTANCE DISTRIBUTION



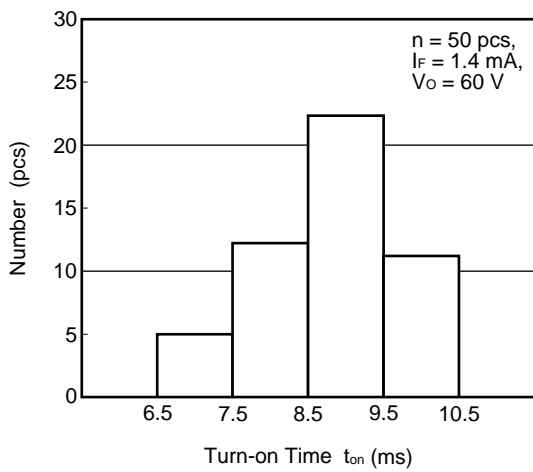
TURN-ON TIME vs. FORWARD CURRENT



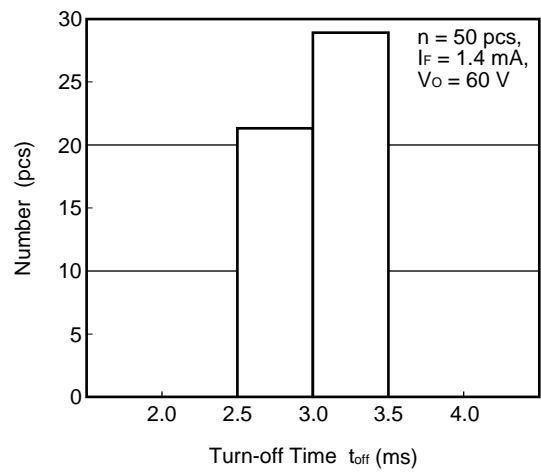
TURN-OFF TIME vs. FORWARD CURRENT



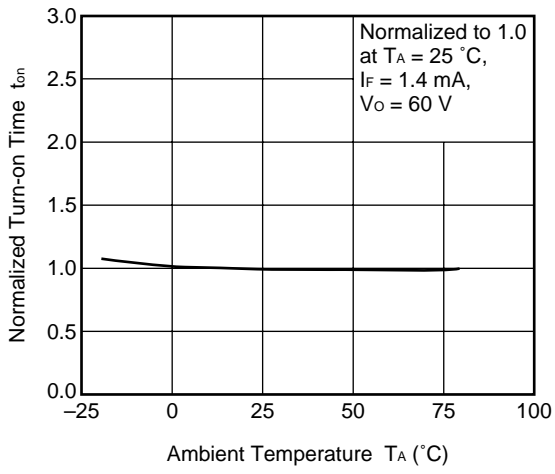
TURN-ON TIME DISTRIBUTION



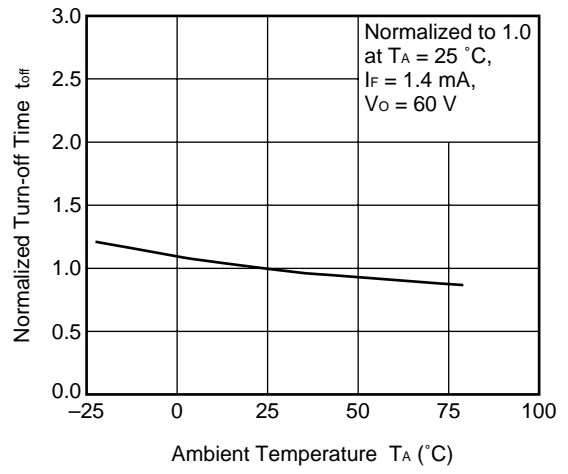
TURN-OFF TIME DISTRIBUTION



NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE



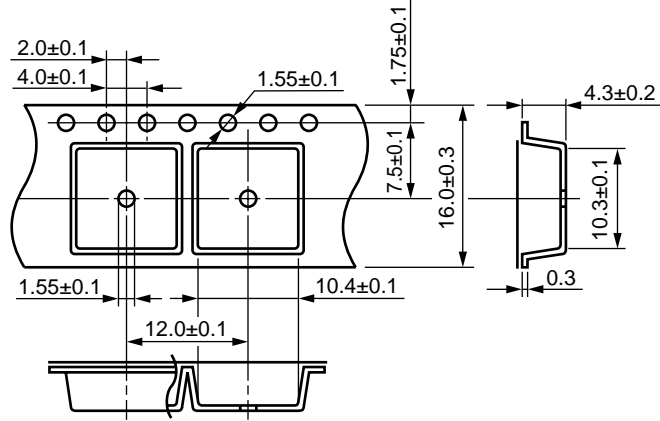
NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



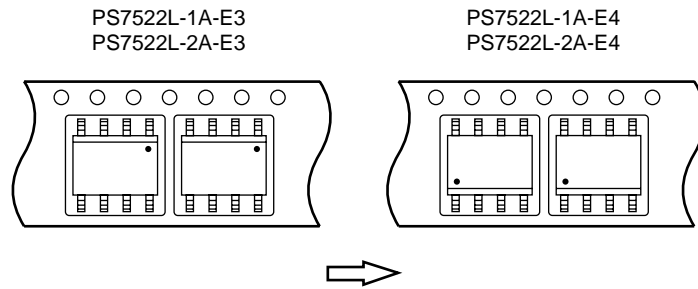
Remark The graphs indicate nominal characteristics.

★ TAPING SPECIFICATIONS (in millimeters)

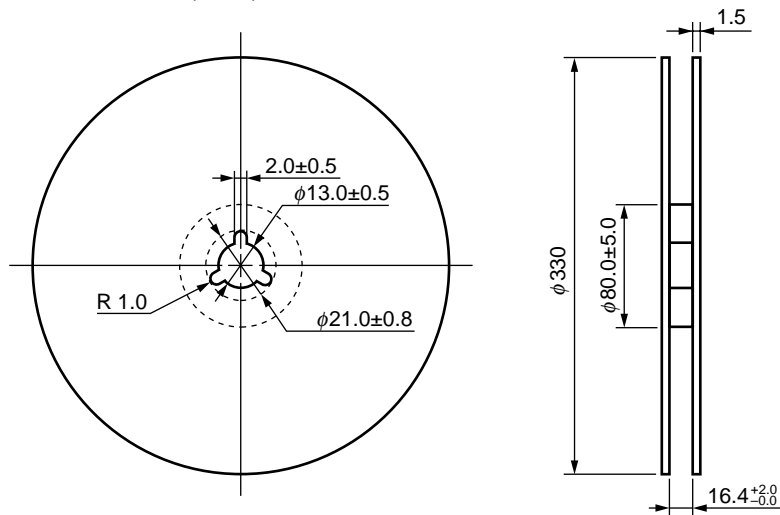
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



Packing: 1 000 pcs/reel

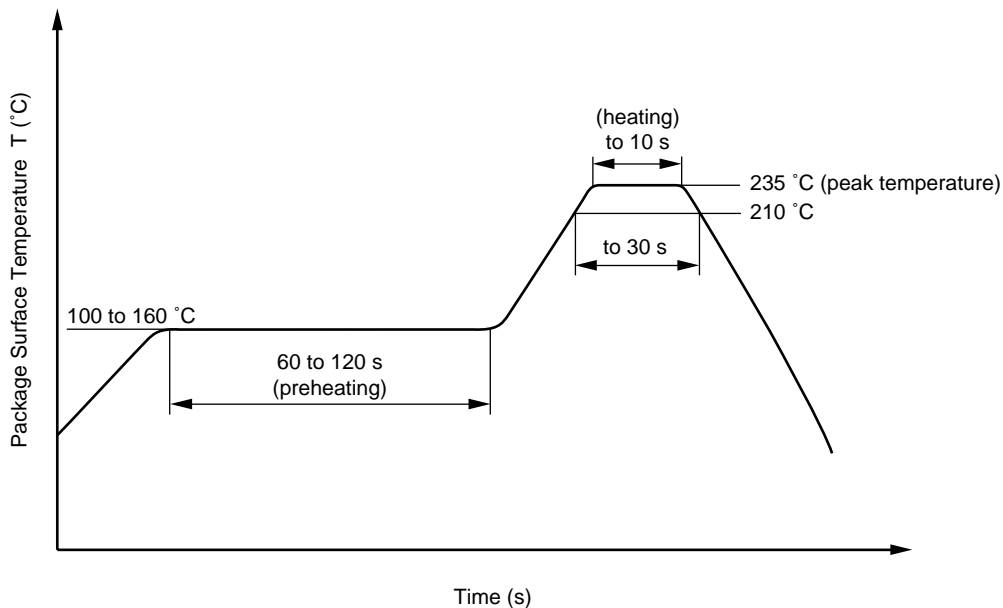
RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

- Peak reflow temperature 235 °C (package surface temperature)
- Time of temperature higher than 210 °C 30 seconds or less
- Number of reflows Two
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

★

Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Number of times One
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

- Fluxes
Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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